

SPICE Device Model Si1330EDL

Vishay Siliconix

N-Channel 60-V (D-S) MOSFET

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

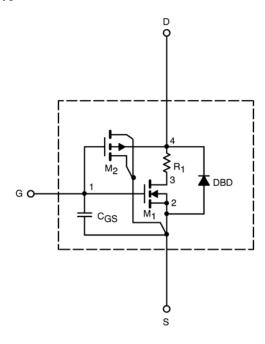
- Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

DESCRIPTION

The attached spice model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to 125°C temperature ranges under the pulsed 0-V to 10-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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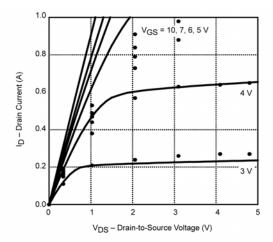
SPECIFICATIONS (T _J = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static			•		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	1.6		V
On-State Drain Current ^a	I _{D(on)}	V _{DS} = 5 V, V _{GS} = 10 V	4		Α
Drain-Source On-State Resistance ^a	r _{DS(on)}	V_{GS} = 10 V, I_{D} = 0.25 A	1.1	1	Ω
		$V_{GS} = 4.5 \text{ V}, I_D = 0.20 \text{ A}$	1.6	1.4	
Forward Transconductance ^a	g _{fs}	V _{DS} = 10 V, I _D = 0.25 A	240	350	mS
Diode Forward Voltage ^a	V_{SD}	I _S = 0.23 A, V _{GS} = 0 V	0.85	0.83	V
Dynamic ^b			•		
Total Gate Charge	Q _g	V_{DS} = 10 V, V_{GS} = 4.5 V, I_{D} = 0.25 A	0.30	0.40	nC
Gate-Source Charge	Q_{gs}		0.11	0.11	
Gate-Drain Charge	Q _{gd}		0.15	0.15	

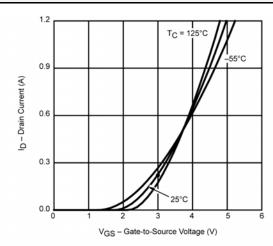
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2\%.$ b. Guaranteed by design, not subject to production testing.

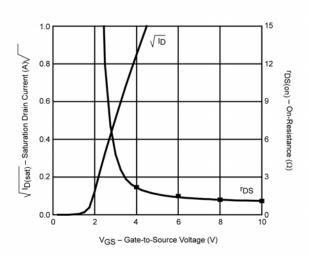


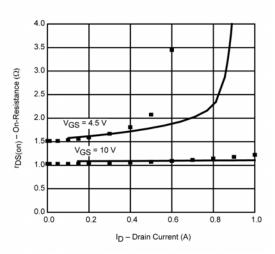
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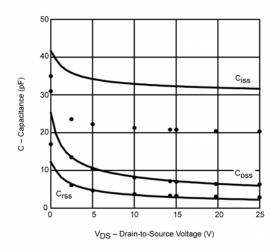
COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)

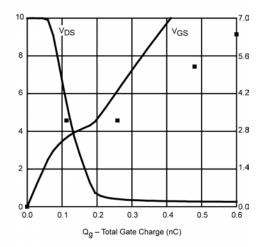












Note: Dots and squares represent measured data.



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